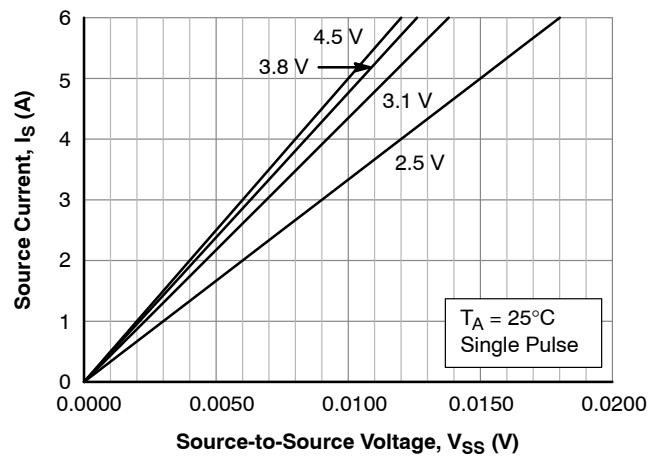
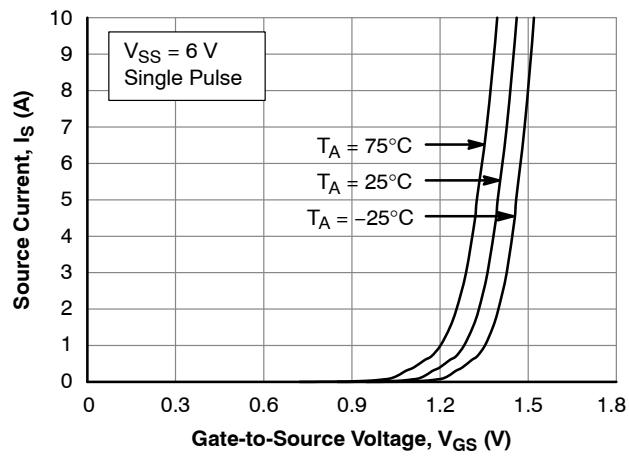
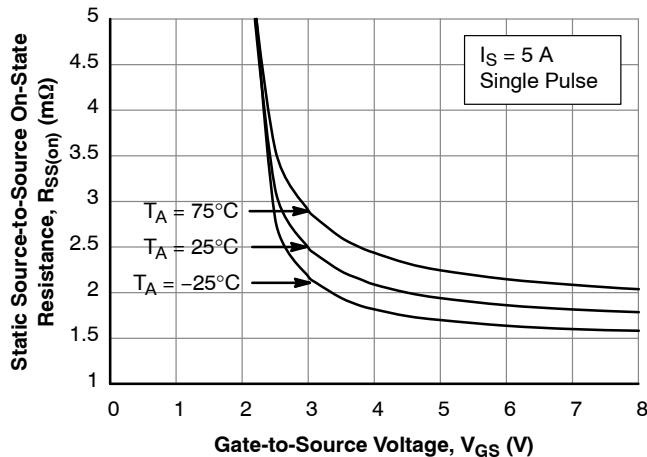
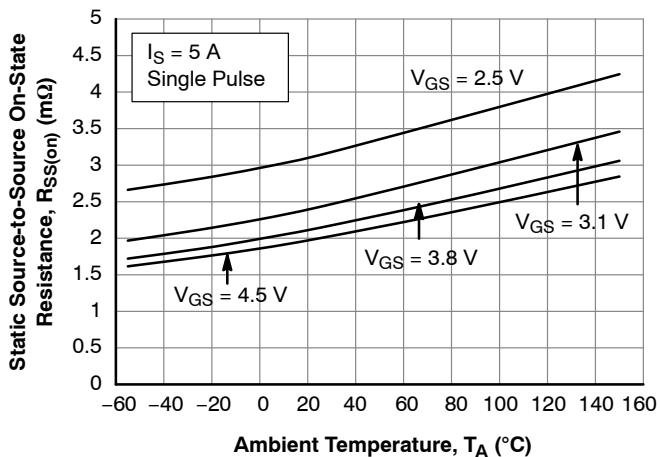
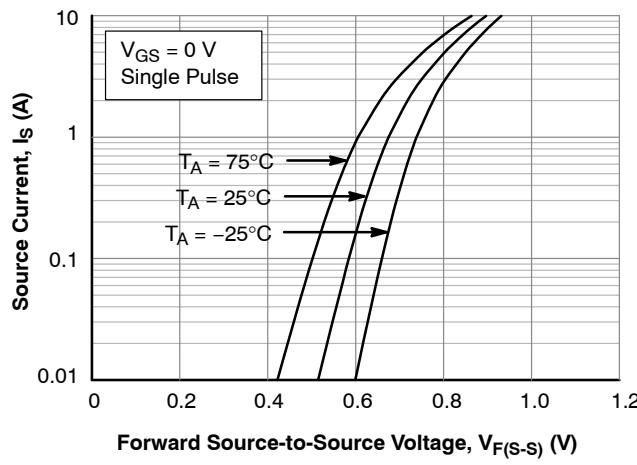
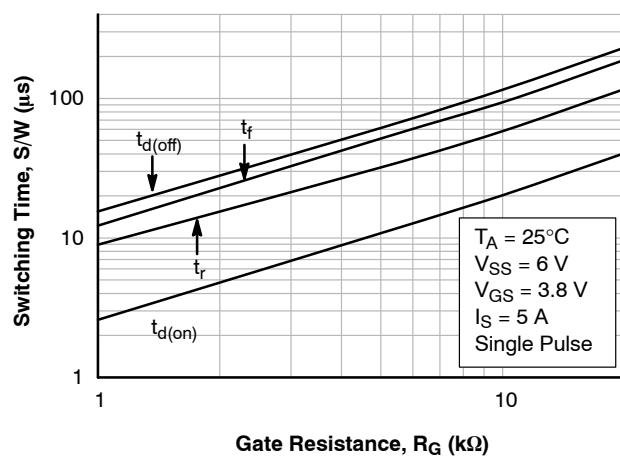


ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$)

Parameter	Symbol	Conditions	Value			Unit	
			Min	Typ	Max		
Source to Source Breakdown Voltage	$V_{(\text{BR})\text{SSS}}$	$I_S = 1 \text{ mA}, V_{GS} = 0 \text{ V}$	Test Circuit 1	12	—	—	V
Zero-Gate Voltage Source Current	I_{SSS}	$V_{SS} = 10 \text{ V}, V_{GS} = 0 \text{ V}$	Test Circuit 1	—	—	1	μA
Gate to Source Leakage Current	I_{GSS}	$V_{GS} = \pm 8 \text{ V}, V_{SS} = 0 \text{ V}$	Test Circuit 2	—	—	± 1	μA
Gate Threshold Voltage	$V_{GS(\text{th})}$	$V_{SS} = 6 \text{ V}, I_S = 1 \text{ mA}$	Test Circuit 3	0.4	—	1.3	V
Static Source to Source On-State Resistance	$R_{\text{SS(on)}}$	$I_S = 5 \text{ A}, V_{GS} = 4.5 \text{ V}$	Test Circuit 4	1.30	2.00	2.65	$\text{m}\Omega$
		$I_S = 5 \text{ A}, V_{GS} = 3.8 \text{ V}$	Test Circuit 4	1.40	2.10	2.75	$\text{m}\Omega$
		$I_S = 5 \text{ A}, V_{GS} = 3.1 \text{ V}$	Test Circuit 4	1.50	2.30	3.75	$\text{m}\Omega$
		$I_S = 5 \text{ A}, V_{GS} = 2.5 \text{ V}$	Test Circuit 4	1.85	3.00	6.00	$\text{m}\Omega$
Turn-ON Delay Time	$t_{\text{d(on)}}$	$V_{SS} = 6 \text{ V}, V_{GS} = 3.8 \text{ V}, I_S = 5 \text{ A}, R_g = 10 \text{ k}\Omega$ Test Circuit 5	—	20	—	μs	
Rise Time	t_r		—	58	—	μs	
Turn-OFF Delay Time	$t_{\text{d(off)}}$		—	115	—	μs	
Fall Time	t_f		—	94	—	μs	
Total Gate Charge	Q_g	$V_{SS} = 6 \text{ V}, V_{GS} = 3.8 \text{ V}, I_S = 5 \text{ A}$	—	42	—	nC	
Forward Source to Source Voltage	$V_{F(S-S)}$	$I_S = 3 \text{ A}, V_{GS} = 0 \text{ V}$ Test Circuit 7	—	0.75	1.2	V	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

TYPICAL CHARACTERISTICS

Figure 1. I_S – V_{SS} Figure 2. I_S – V_{GS} Figure 3. $R_{SS(on)}$ – V_{GS} Figure 4. $R_{SS(on)}$ – T_A Figure 5. I_S – $V_{F(S-S)}$ Figure 6. S/W Time – R_G

TYPICAL CHARACTERISTICS (Continued)

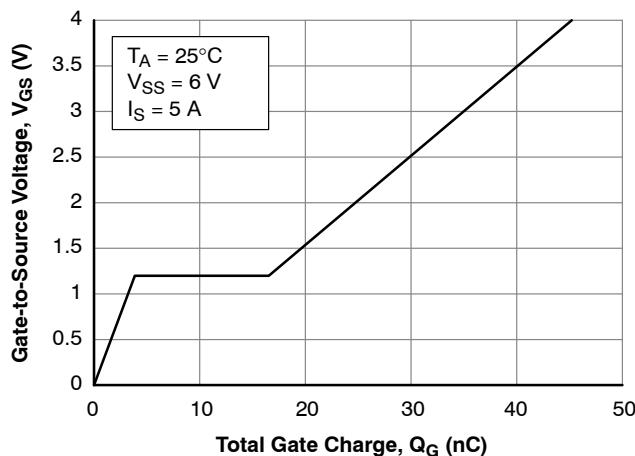


Figure 7. V_{GS} – Q_G

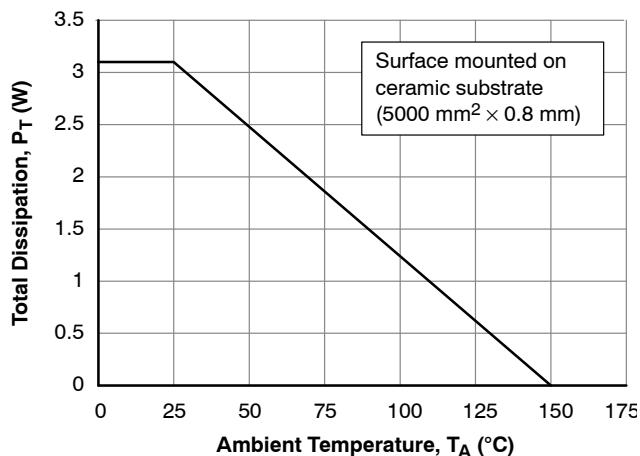


Figure 8. P_T – T_A

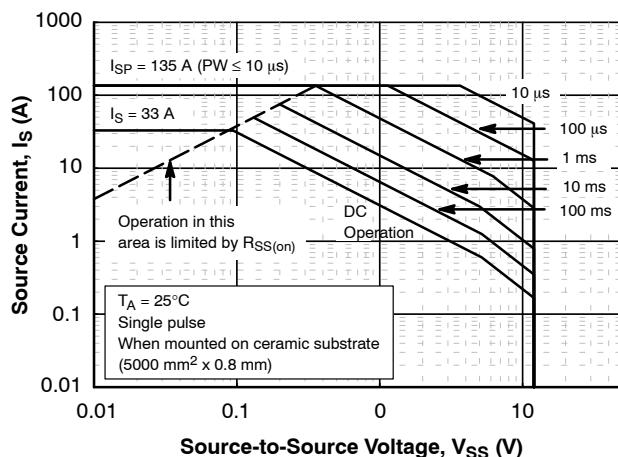


Figure 9. Safe Operating Area

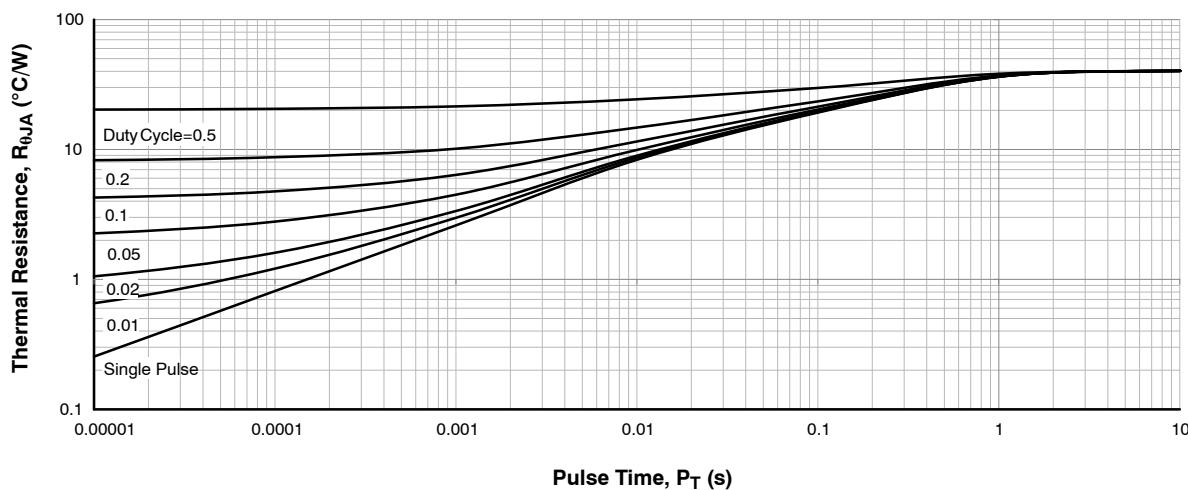
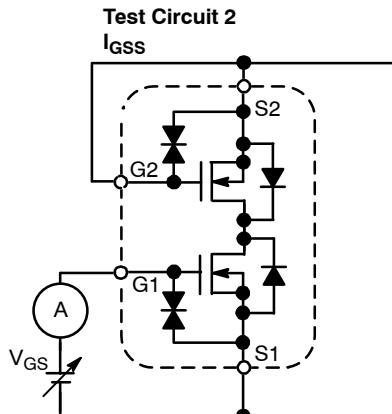
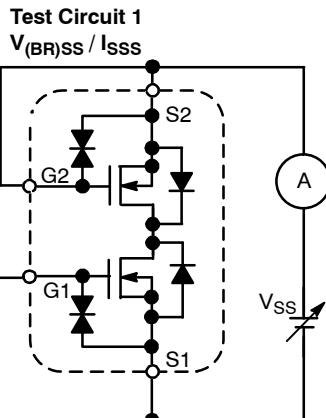
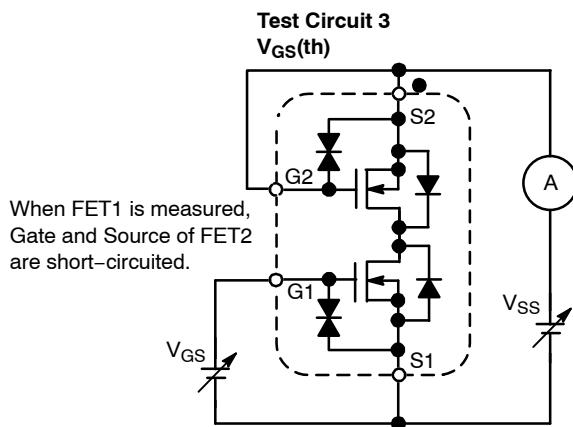


Figure 10. Thermal Response

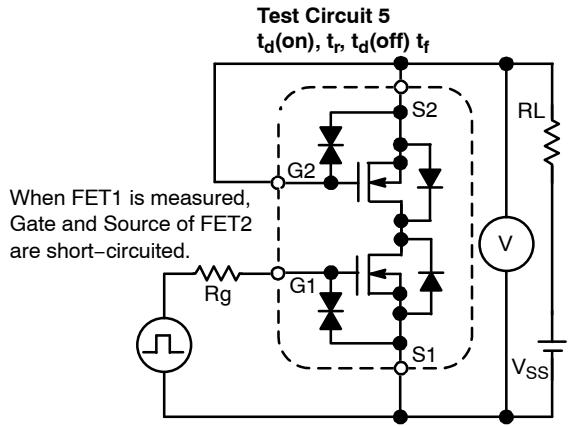
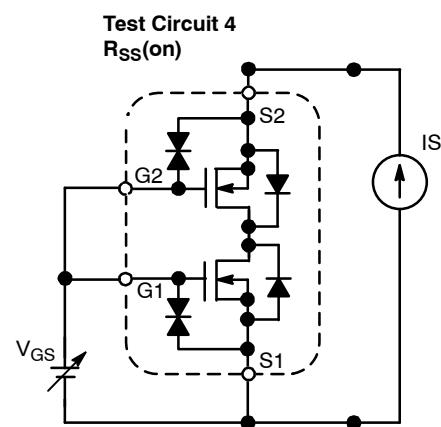
Test Circuits are Example of Measuring FET1 Side



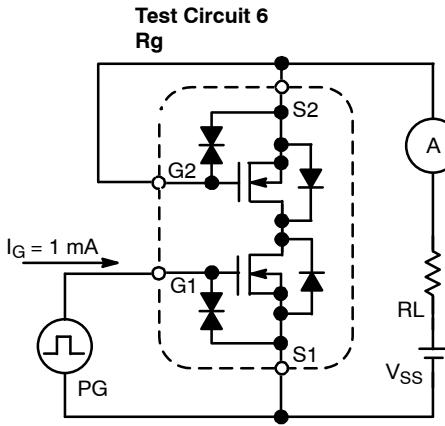
When FET1 is measured,
 Gate and Source of FET2
 are short-circuited.



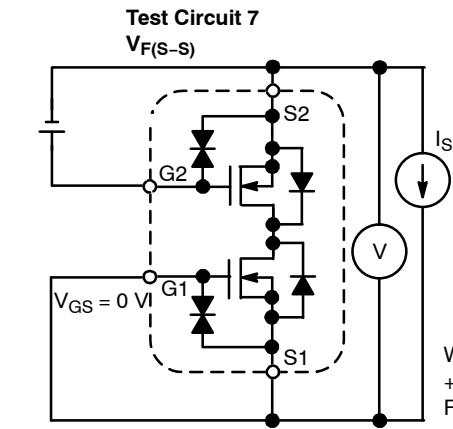
When FET1 is measured,
 Gate and Source of FET2
 are short-circuited.



When FET1 is measured,
 Gate and Source of FET2
 are short-circuited.



When FET1 is measured,
 Gate and Source of FET2
 are short-circuited.



When FET1 is measured,
 +4.5 V is added to V_{GS} of
 FET2.

EFC2K102NUZ

ORDERING INFORMATION

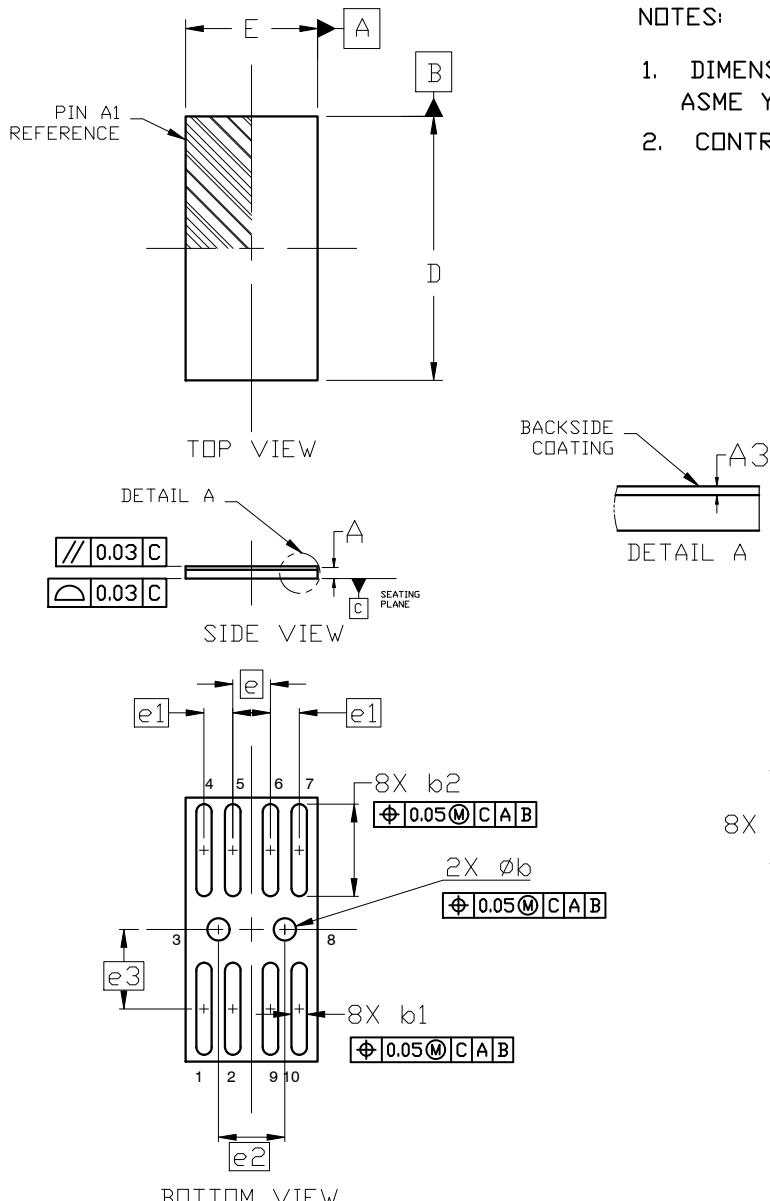
Device	Marking	Package	Shipping (Qty / Packing) [†]
EFC2K102NUZTDG	PA	WLCSP10, 2.98x1.49x0.140 (Pb-Free / Halogen Free)	5,000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

NOTE: Since the EFC2K102NUZ is a MOSFET product, please avoid using this device in the vicinity of highly charged objects. Please contact sales for use except the designated application.

WLCSP10, 2.98x1.49x0.14
CASE 567XC
ISSUE O

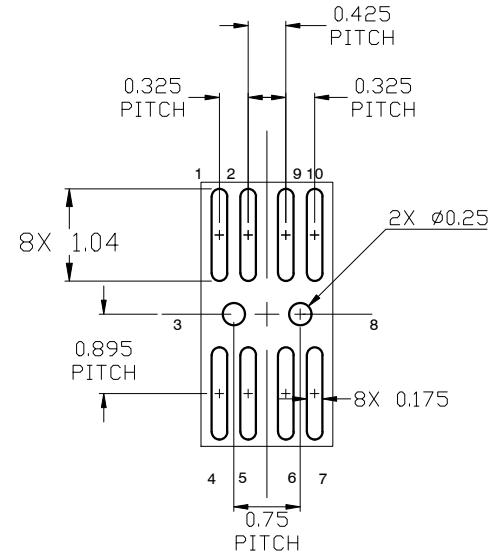
DATE 19 OCT 2018



NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS

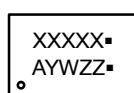
DIM	MILLIMETERS		
	MIN.	NOM.	MAX.
A	0.11	0.14	0.17
A3		0.04	REF
b	0.22	0.25	0.28
b1	0.145	0.175	0.205
b2	1.01	1.04	1.07
D	2.95	2.98	3.01
E	1.46	1.49	1.52
e	0.425	BSC	
e1	0.325	BSC	
e2	0.75	BSC	
e3	0.895	BSC	



**RECOMMENDED
MOUNTING FOOTPRINT***

* For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERM/D.

**GENERIC
MARKING DIAGRAM***



XXXX = Specific Device Code
A = Assembly Location
Y = Year
W = Work Week
ZZ = Assembly Lot Code
■ = Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

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DESCRIPTION:	WLCSP10, 2.98x1.49x0.14	PAGE 1 OF 1

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